

(6N137)

DIGITAL LOGIC ISOLATION.

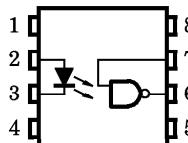
TELE-COMMUNICATION.

ANALOG DATA EQUIPMENT CONTROL

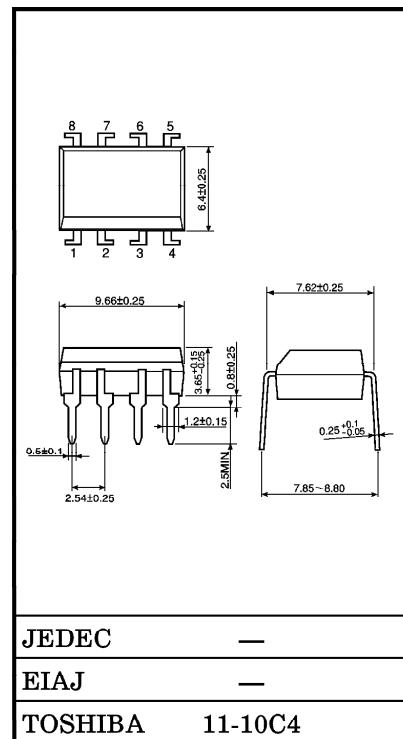
The TOSHIBA 6N137 consist of a high emitting diode and a one chip photo IC. This unit is 8-lead DIP package.

- LSTTL/TTL Compatible : 5V Supply
- Ultra High Speed : 10 MBd
- Guaranteed Performance Over Temperature : 0 °C to 70 °C
- High Isolation Voltage : 2500VRms Min.
- UL Recognized : UL1577, File No. E67349

PIN CONFIGURATIONS (TOP VIEW)



- |   |         |   |                        |
|---|---------|---|------------------------|
| 1 | N.C.    | 5 | GND                    |
| 2 | ANODE   | 6 | OUTPUT(OPEN COLLECTOR) |
| 3 | CATHODE | 7 | ENABLE                 |
| 4 | N.C.    | 8 | VCC                    |

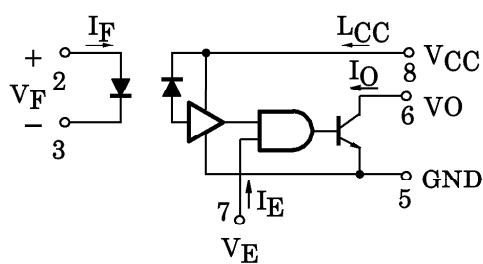


JEDEC —  
EIAJ —  
TOSHIBA 11-10C4

Weight : 0.54g

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	MAX.	UNIT
Input Current, Low Level Each Channel	$I_{FL}$	0	250	$\mu A$
Input Current, High Level Each Channel	$I_{FH}$	7	20	mA
High Level Enable Voltage	$V_{EH}$	2.0	$V_{CC}$	V
Low Level Enable Voltage (Output High)	$V_{EL}$	0	0.8	V
Supply Voltage, Output	$V_{CC}$	4.5	5.5	V
Fan Out(TTL LOAD)	N	—	8	—
Operating Temperature	$T_a$	0	70	°C



TRUTH TABLE

INPUT	ENABLE	OUTPUT
H	H	L
L	H	H
H	L	H
L	L	H

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**MAXIMUM RATINGS**

CHARACTERISTIC		SYMBOL	RATING	UNIT
<b>LED</b>	Forward Current	I <sub>F</sub>	20	mA
	Pulse Forward Current (Note 1)	I <sub>FP</sub>	40	mA
	Reverse Voltage	V <sub>R</sub>	5	V
<b>DETECTOR</b>	Output Current	I <sub>O</sub>	50	mA
	Output Voltage	V <sub>O</sub>	7	V
	Supply Voltage (1 minute Maximum)	V <sub>CC</sub>	7	V
	Enable Input Voltage (Not to exceed V <sub>CC</sub> by more than 500mV)	V <sub>EH</sub>	5.5	V
	Output Collector Power Dissipation	P <sub>O</sub>	85	mW
Operating Temperature Range		T <sub>opr</sub>	0~70	°C
Storage Temperature Range		T <sub>stg</sub>	-55~125	°C
Lead Solder Temperature (10s) (Note 2)		T <sub>sol</sub>	260	°C

Note 1 : 50% duty cycle, 1ms Pulse width.

Note 2 : Soldering portion of lead : up to 2mm from the body of the device.

**PRECAUTION**

Please be careful of the followings.

A ceramic capacitor (0.1μF) should be connected from pin 8 to pin 5 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property. The total lead length between capacitor and coupler should not exceed 1cm.

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ELECTRICAL CHARACTERISTICS

OVER RECOMMENDED TEMPERATURE ( $T_a = 0 \sim 70^\circ\text{C}$  Unless otherwise noted)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	***TYP.	MAX.	UNIT
High Level Output Current	$I_{OH}$	$V_{CC} = 5.5\text{V}$ , $V_O = 5.5\text{V}$ $I_F = 250\mu\text{A}$ , $V_E = 2.0\text{V}$	—	1	250	$\mu\text{A}$
Low Level Output Voltage	$V_{OL}$	$V_{CC} = 5.5\text{V}$ , $I_F = 5\text{mA}$ $V_{EH} = 2.0\text{V}$ $I_{OL}$ (Sinking) = 13mA	—	0.4	0.6	V
High Level Enable Current	$I_{EH}$	$V_{CC} = 5.5\text{V}$ , $V_E = 2.0\text{V}$	—	-1.0	—	mA
Low Level Enable Current	$I_{EL}$	$V_{CC} = 5.5\text{V}$ , $V_E = 0.5\text{V}$	—	-1.6	-2.0	mA
High Level Supply Current	$I_{CCH}$	$V_{CC} = 5.5\text{V}$ , $I_F = 0$ , $V_E = 0.5\text{V}$	—	7	15	mA
Low Level Supply Current	$I_{CCL}$	$V_{CC} = 5.5\text{V}$ , $I_F = 10\text{mA}$ $V_E = 0.5\text{V}$	—	12	18	mA
Resistance (Input-Output) (Note)	$R_{I-O}$	$V_{I-O} = 500\text{V}$ , $T_a = 25^\circ\text{C}$ R.H. $\leq 60\%$	—	$10^{12}$	—	$\Omega$
Capacitance (Input-Output) (Note)	$C_{I-O}$	$f = 1\text{MHz}$ , $T_a = 25^\circ\text{C}$	—	0.6	—	pF
Input Forward Voltage	$V_F$	$I_F = 10\text{mA}$ , $T_a = 25^\circ\text{C}$	—	1.65	1.75	V
Input Reverse Breakdown Voltage	$BV_R$	$I_R = 10\mu\text{A}$ , $T_a = 25^\circ\text{C}$	5	—	—	V
Input Capacitance	$C_{IN}$	$V_F = 0$ , $f = 1\text{MHz}$	—	45	—	pF
Current Transfer Ratio	$CTR$	$I_F = 5.0\text{mA}$ , $R_L = 100\Omega$	—	1000	—	%

※※ All typical values are at  $V_{CC} = 5\text{V}$ ,  $T_a = 25^\circ\text{C}$

Note : Pins 1, 2, 3 and 4 shorted together and Pins 5, 6, 7 and 8 shorted together.

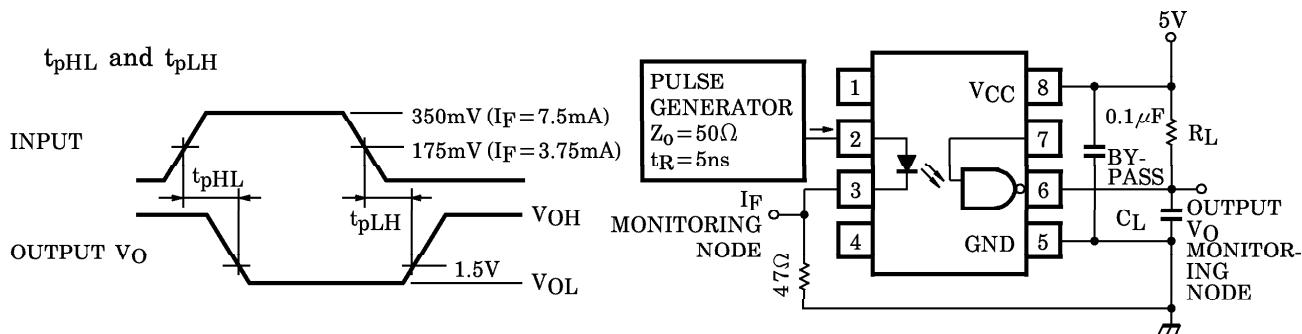
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SWITCHING CHARACTERISTICS ( $T_a = 25^\circ C$ ,  $V_{CC} = 5V$ )

CHARACTERISTIC	SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Propagation Delay Time to High Output Level	$t_{pLH}$	1	$R_L = 350\Omega$ , $C_L = 15pF$ $I_F = 7.5mA$	—	60	75	ns
Propagation Delay Time to Low Output Level	$t_{pHL}$	1	$R_L = 350\Omega$ , $C_L = 15pF$ $I_F = 7.5mA$	—	60	75	ns
Output Rise-Fall Time (10-90%)	$t_r, t_f$	—	$R_L = 350\Omega$ , $C_L = 15pF$ $I_F = 7.5mA$	—	30	—	ns
Propagation Delay Time of Enable from $V_{EH}$ to $V_{EL}$	$t_{ELH}$	2	$R_L = 350\Omega$ , $C_L = 15pF$ $I_F = 7.5mA$ $V_{EH} = 3.0V$ $V_{EL} = 0.5V$	—	25	—	ns
Propagation Delay Time of Enable from $V_{EL}$ to $V_{EH}$	$t_{EHL}$	2	$R_L = 350\Omega$ , $C_L = 15pF$ $I_F = 7.5mA$ $V_{EH} = 3.0V$ $V_{EL} = 0.5V$	—	25	—	ns
Common Mode Transient Immunity at Logic High Output Level	$CM_H$	3	$V_{CM} = 10V$ $R_L = 350\Omega$ $V_O(\text{min.}) = 2V$ $I_F = 0mA$	—	200	—	$V/\mu s$
Common Mode Transient Immunity at Logic Low Output Level	$CM_L$	3	$V_{CM} = 10V$ $R_L = 350\Omega$ $V_O(\text{max.}) = 0.8V$ $I_F = 5mA$	—	-500	—	$V/\mu s$

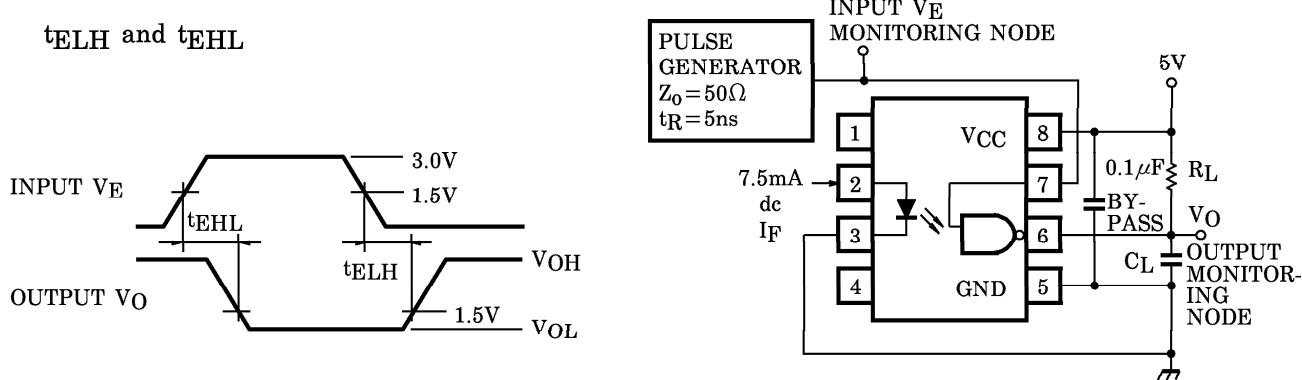
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TEST CIRCUIT 1.



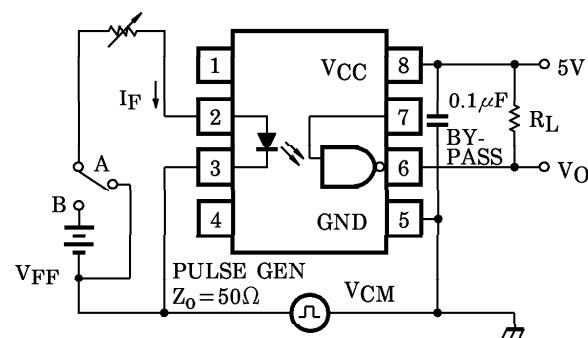
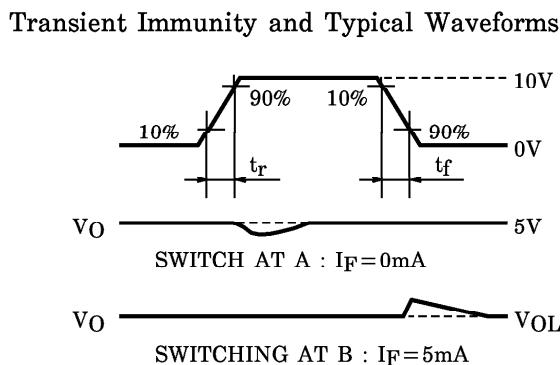
- $C_L$  is approximately 15pF which includes probe and stray wiring capacitance.

TEST CIRCUIT 2.

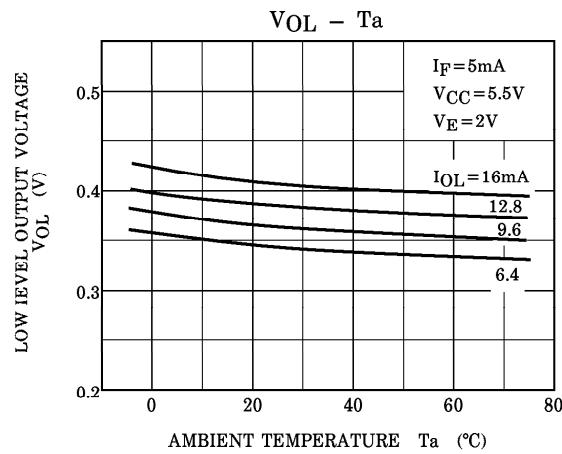
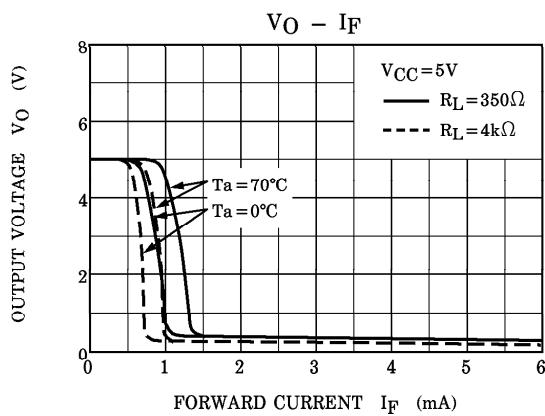
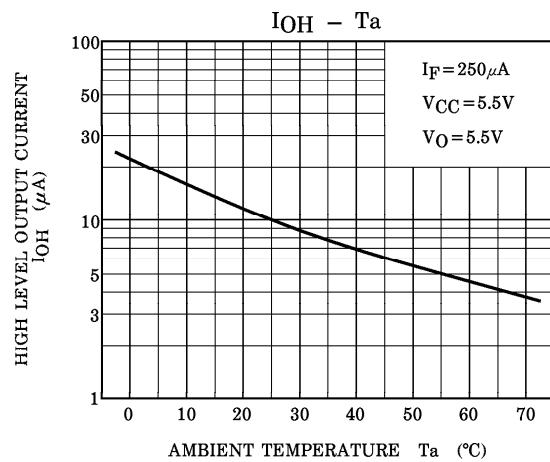
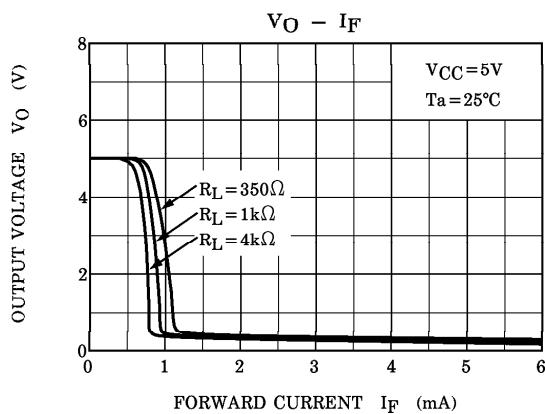
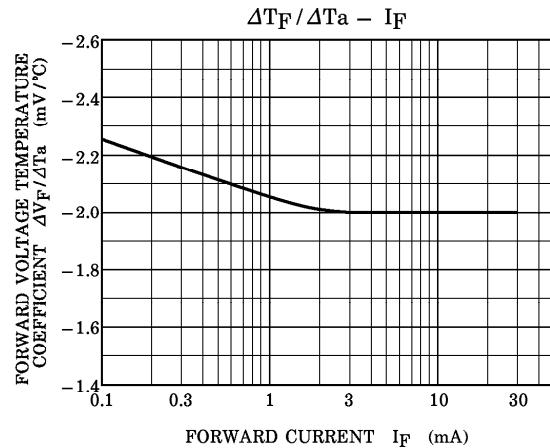
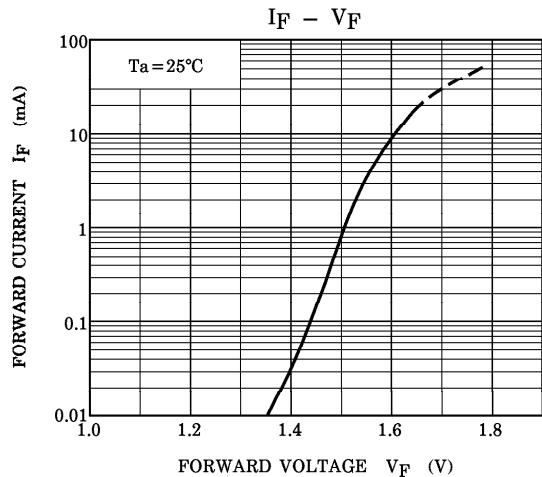


- $C_L$  is approximately 15pF which includes probe and stray wiring capacitance.

TEST CIRCUIT 3.



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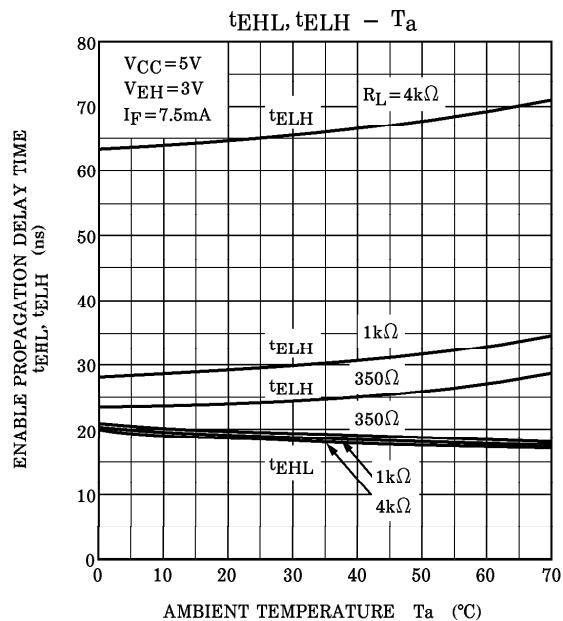
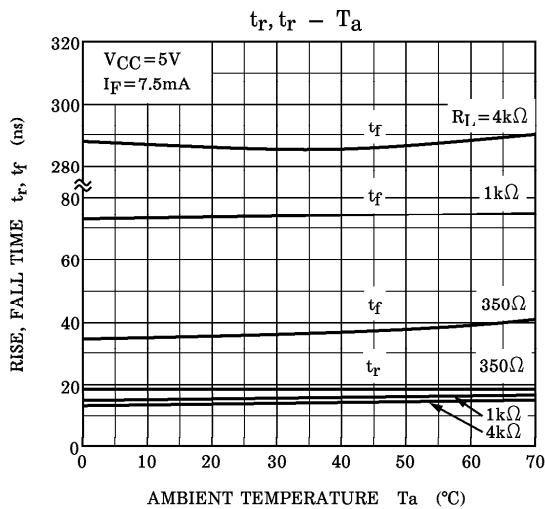
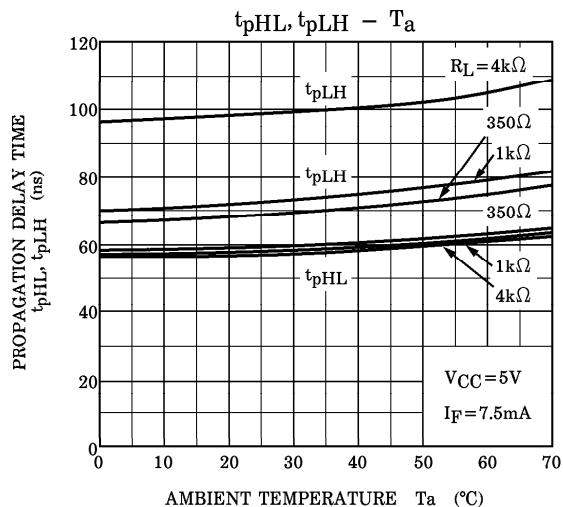
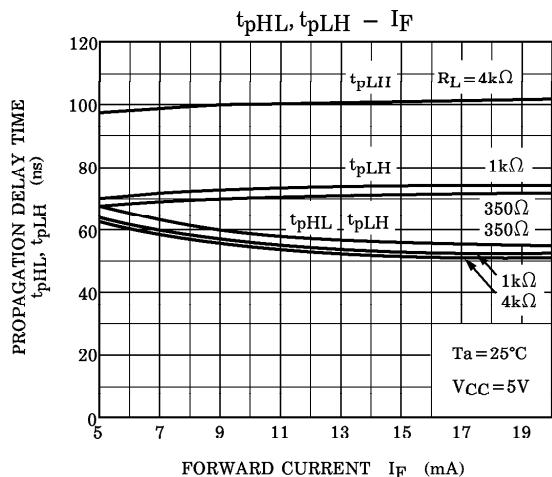


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